30 V, 2 A ultra low V<sub>F</sub> MEGA Schottky barrier rectifiers

Rev. 04 — 4 February 2010 Product de

Product data sheet

#### 1. **Product profile**

## 1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifiers with an integrated guard ring for stress protection encapsulated in small SMD plastic packages.

Table 1. **Product overview** 

Type number	Package		Configuration
	NXP	JEITA	
PMEG3020EH	SOD123F	-	single isolated diodes
PMEG3020EJ	SOD323F	SC-90	single isolated diodes

### 1.2 Features

Forward current: 2 A

Reverse voltage: 30 V

Ultra low forward voltage

Small and flat lead SMD package

## 1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switched-mode power supply
- Inverse polarity protection
- Low power consumption applications

### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>F</sub>	forward current	$T_{sp} \le 55  ^{\circ}C$	-	-	2	Α
$V_R$	reverse voltage		-	-	30	V
$V_{F}$	forward voltage	$I_F = 2000 \text{ mA}$	<u>[1]</u> -	510	620	mV

<sup>[1]</sup> Pulse test:  $t_0 \le 300 \ \mu s; \ \delta \le 0.02$ .



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## 2. Pinning information

Table 3. Pinning

	3	
Pin	Description	Simplified outline Symbol
1	cathode	[1]
2	anode	1 <del>1</del> 2 sym001
		001aab540

<sup>[1]</sup> The marking bar indicates the cathode.

## 3. Ordering information

Table 4. Ordering information

Type number	Package	Package			
	Name	Description	Version		
PMEG3020EH	-	plastic surface mounted package; 2 leads	SOD123F		
PMEG3020EJ	SC-90	plastic surface mounted package; 2 leads	SOD323F		

## 4. Marking

Table 5. Marking codes

Type number	Marking code
PMEG3020EH	A7
PMEG3020EJ	E9

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## 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{R}$	reverse voltage		-	30	V
I <sub>F</sub>	forward current	T <sub>sp</sub> ≤ 55 °C	-	2	Α
I <sub>FRM</sub>	repetitive peak forward current	$t_p \leq 1 \text{ ms; } \delta \leq 0.25$	-	4.5	Α
I <sub>FSM</sub>	non-repetitive peak forward current	t = 8 ms; square wave	[1] -	9	Α
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$			
	PMEG3020EH		<u>[1]</u> _	375	mW
			[2] _	830	mW
	PMEG3020EJ		<u>[1]</u> _	360	mW
			[2] _	830	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

## 6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air					
	PMEG3020EH		[1][2]	-	-	330	K/W
			[2][3]	-	-	150	K/W
	PMEG3020EJ		[1][2]	-	-	350	K/W
			[2][3]	-	-	150	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point						
	PMEG3020EH			-	-	60	K/W
	PMEG3020EJ			-	-	55	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1cm<sup>2</sup>.

<sup>[2]</sup> For Schottky barrier diodes thermal run-away has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses. Nomograms for determining the reverse power losses P<sub>R</sub> and I<sub>F(AV)</sub> rating will be available on request.

<sup>[3]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1cm<sup>2</sup>.

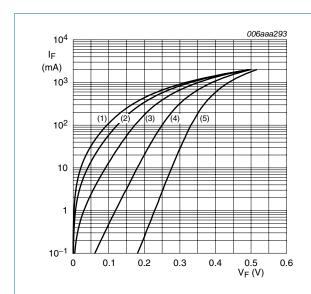
## 7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{F}$	forward voltage		<u>[1]</u>			
		I <sub>F</sub> = 1 mA	-	125	160	mV
		I <sub>F</sub> = 10 mA	-	185	220	mV
		I <sub>F</sub> = 100 mA	-	255	290	mV
		I <sub>F</sub> = 500 mA	-	330	380	mV
		$I_F = 1000 \text{ mA}$	-	400	480	mV
		$I_F = 2000 \text{ mA}$	-	510	620	mV
$I_R$	reverse current	V <sub>R</sub> = 10 V	-	60	150	μΑ
		V <sub>R</sub> = 30 V	-	400	1000	μΑ
C <sub>d</sub>	diode capacitance	$V_R = 1 V$ ; $f = 1 MHz$	-	60	72	pF

[1] Pulse test:  $t_0 \le 300 \ \mu s; \ \delta \le 0.02$ .



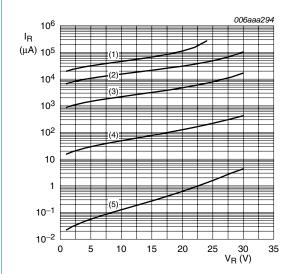


<sup>(2)</sup> T<sub>amb</sub> = 125 °C

(4) 
$$T_{amb} = 25 \, ^{\circ}C$$

(5)  $T_{amb} = -40 \, ^{\circ}C$ 

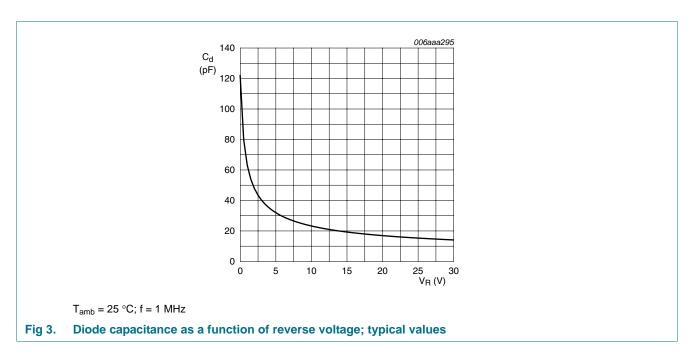
Fig 1. Forward current as a function of forward voltage; typical values



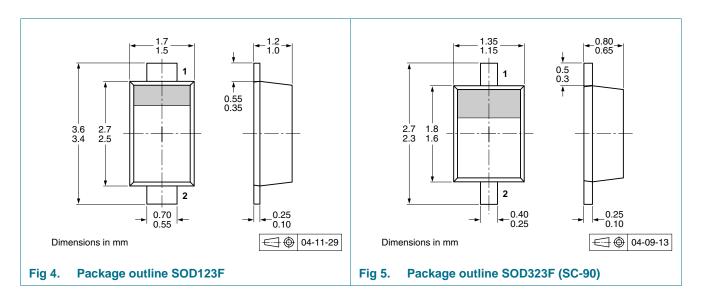
- (1)  $T_{amb} = 150 \, ^{\circ}C$
- (2)  $T_{amb} = 125 \, ^{\circ}C$
- (3)  $T_{amb} = 85 \, ^{\circ}C$
- (4)  $T_{amb} = 25 \, ^{\circ}C$
- (5)  $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values

<sup>(3)</sup>  $T_{amb} = 85 \, ^{\circ}C$ 



## 8. Package outline



## 9. Packing information

Table 9. Packing methods

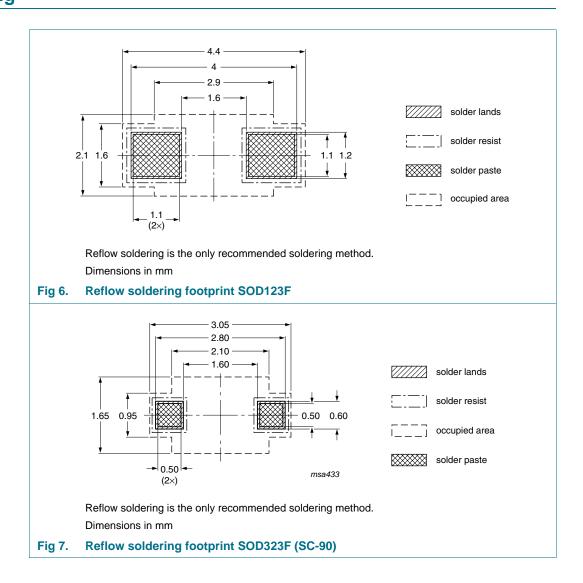
The -xxx numbers are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
PMEG3020EH	SOD123F	4 mm pitch, 8 mm tape and reel	-115	-135
PMEG3020EJ	SOD323F	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see Section 13.

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## 10. Soldering



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## 11. Revision history

### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG3020EH_EJ_4	20100204	Product data sheet	-	PMEG3020EH_EJ_3
Modifications:		et was changed to reflect to legal definitions and discl		
PMEG3020EH_EJ_3	20050531	Product data sheet	-	PMEG3020EH_EJ_2
PMEG3020EH_EJ_2	20050404	Product data sheet	-	PMEG3020EJ_1
PMEG3020EJ_1	20050125	Product data sheet	-	-

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## 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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## **NXP Semiconductors**

# PMEG3020EH; PMEG3020EJ

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